

Primary side startup controller

General description

EZ-PD™ PAG1P (**P**ower **A**dapter **G**eneration **1** **P**imary) is Infineon's primary-side start-up controller for AC/DC applications targeting the mobile power adapter segment. EZ-PD™ PAG1P interfaces directly with either the AC mains in an X-cap discharge mode or the DC output of a bridge rectifier. EZ-PD™ PAG1P is available in a 10-pin SOIC package.

EZ-PD™ PAG1P is designed for a secondary controlled AC/DC flyback converter topology. In this topology, voltage and current regulation is performed by the secondary controller. EZ-PD™ PAG1P is responsible for providing the start-up function, driving the primary side FET as well as responding to fault conditions.

Features

- Works across universal AC mains input 85 VAC to 265 VAC
- Low-side gate driver to drive primary side FET
- Line undervoltage protection (UVP) and line overvoltage protection
- Overcurrent protection (OCP)
- Overvoltage protection (OVP) during soft-start
- Programmable soft-start configurable with external capacitor
- Fixed auto-restart timer for fault recovery
- Supports X-cap discharge mode to obtain better efficiency
- Integrated high-voltage start-up and shunt regulator
- Synchronizes to PWM from secondary side using a pulse edge Transformer

Functional block diagram

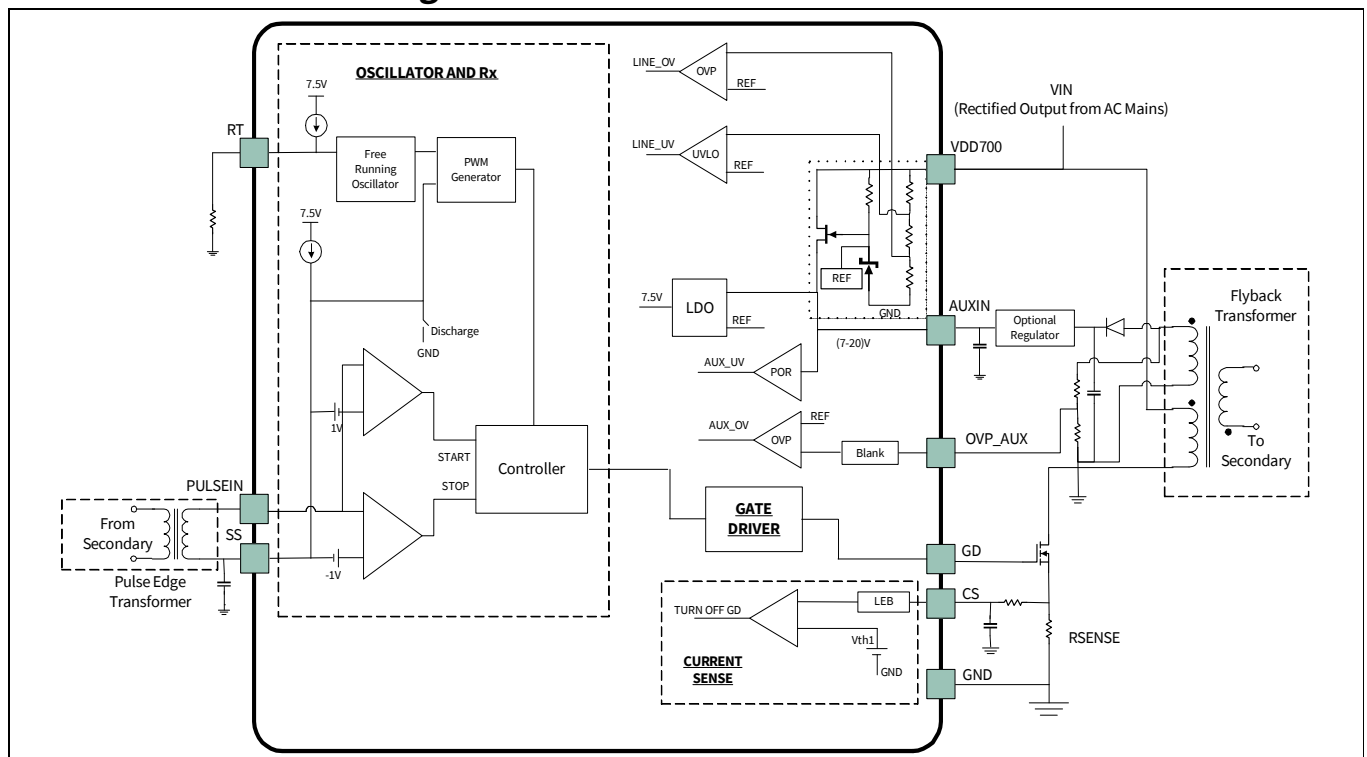


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Pinout

1 Pinout

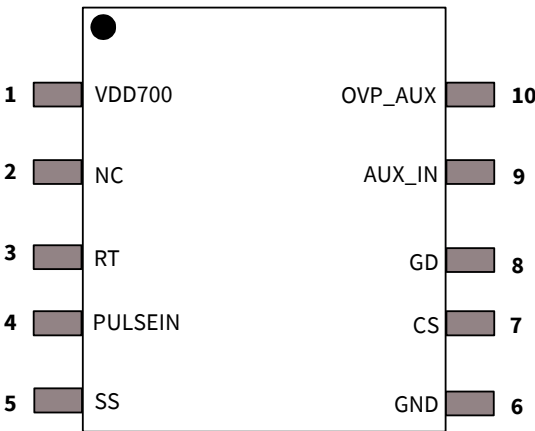


Figure 1 Pin map

Table 1 EZ-PD™ PAG1P pin description

Pin number	Pin name	Description
1	VDD700	Start-up power supply input. VDD700 is the power supply source during the start-up phase. This pin can be connected to either the bridge rectifier output as shown in Figure 2 , or directly to the AC mains through a diode as shown in Figure 3 . This pin has a maximum voltage rating of 500 V.
2	NC	No connect
3	RT	Timing resistor. The RT pin is used to connect to an external timing resistor of 499 kΩ which determines the free running oscillator frequency Fosc. Oscillator frequency is typically 30 kHz.
4	PULSEIN	Pulse Edge Transformer (PET) input. Once the start-up phase is successfully complete, EZ-PD™ PAG1P synchronizes to the secondary side pulses received at the PULSEIN input. The secondary controller provides PWM control information to the primary using a PET. The pulse amplitude shall not exceed V_PULSEINNEGAMP and V_PULSEINPOSAMP and the pulse width shall be in the T_PULSEINPW range.
5	SS	Soft-start pin. Connect a 0.1-μF capacitor to GND. The soft-start time is provided in the specification section (Table 13). This pin also connects to the other end of the pulse transformer. The external capacitor connected to the SS pin determines the soft-start time. The duty cycle of the gate drive gradually increases to provide a smooth transfer of power to the secondary side.
6	GND	Ground
7	CS	Primary side current sense input. Current sense input is used to monitor the overcurrent fault scenario. Overcurrent fault is detected with the voltage between this input and ground exceeds V_CSTH1 threshold.
8	GD	Primary FET gate driver. EZ-PD™ PAG1P integrates a low side gate driver to drive the gate of an external FET.

Pinout

Table 1 **EZ-PD™ PAG1P pin description** *(continued)*

Pin number	Pin name	Description
9	AUX_IN	Auxiliary supply input. AUX_IN serves as the power supply source after the start-up phase. This pin should be connected to the output of auxiliary winding through a rectifier or a regulator depending on whether the maximum voltage on the output of the auxiliary winding exceeds 22 V. EZ-PD™ PAG1P switches its power supply source to AUX_IN once the secondary side provides power.
10	OVP_AUX	Auxiliary winding overvoltage detection. EZ-PD™ PAG1P monitors this pin for overvoltage condition on the secondary side, using an external resistor divider. Any voltage exceeding V_OVPAUXRISE on this pin is treated as an overvoltage fault condition. The overvoltage condition is monitored only during open loop operation. A Schottky diode to GND should be connected to ensure negative voltage is not seen when the gate driver is ON.

2 Application overview

EZ-PD™ PAG1P works with Infineon's secondary side controller EZ-PD™ PAG1S. **Figure 2** shows the application diagram of a USB Power Delivery power adapter solution with 'EZ-PD™ PAG1P + EZ-PD™ PAG1S'. In this system, once the start-up phase is complete, the primary FET control is completely synchronized to the PWM pulses received from the secondary side. The PWM pulses are transmitted over an isolation barrier using a PET. EZ-PD™ PAG1P takes over control of the primary FET only during power-up and system fault scenarios.

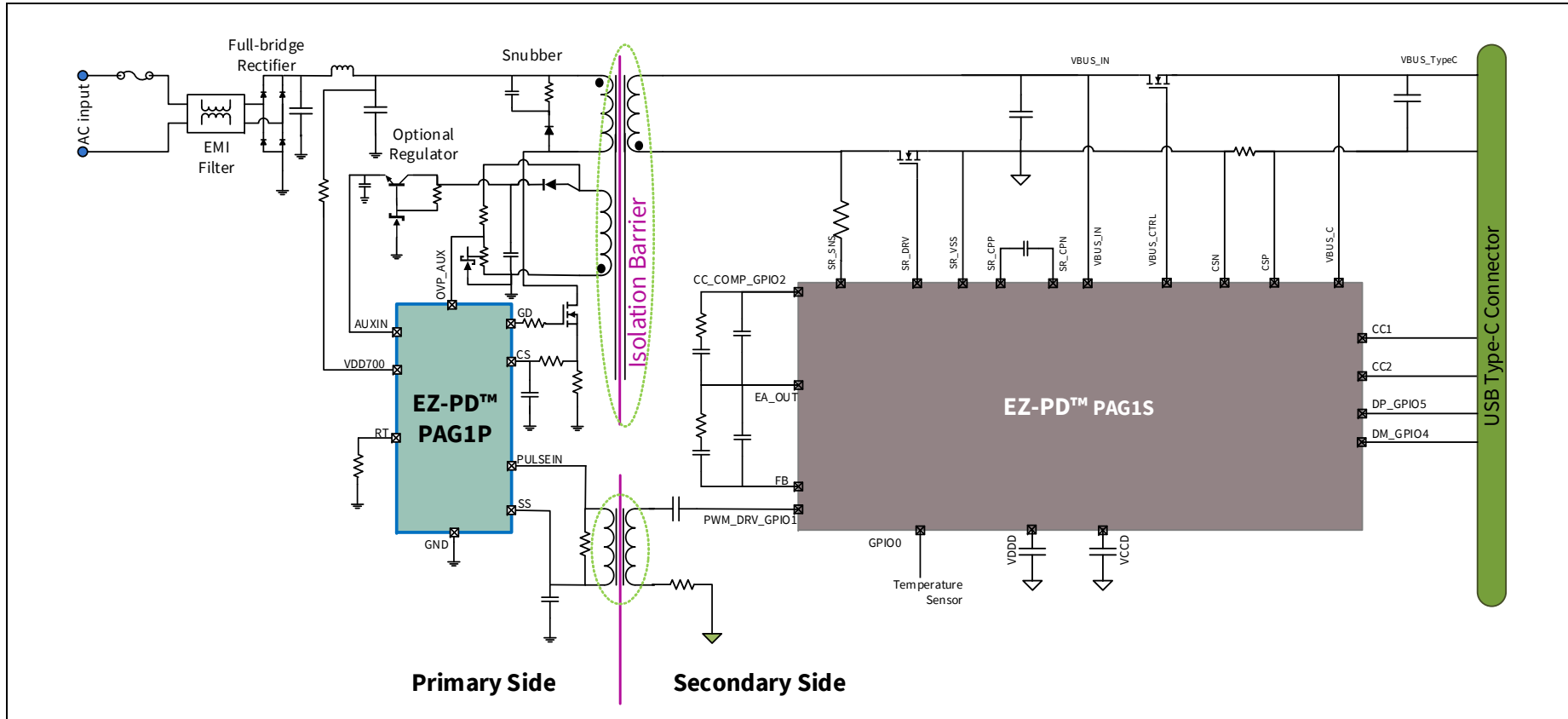


Figure 2 Type-C based mobile phone power adapter with EZ-PD™ PAG1P (CYPAP111xx) and EZ-PD™ PAG1S in a secondary controlled flyback topology configuration

Figure 3 shows the application diagram for a power adapter where EZ-PD™ PAG1P is powered directly from the AC mains before the full bridge rectifier. This topology enables discharging the X cap using EZ-PD™ PAG1P instead of using a passive resistor thereby improving efficiency.

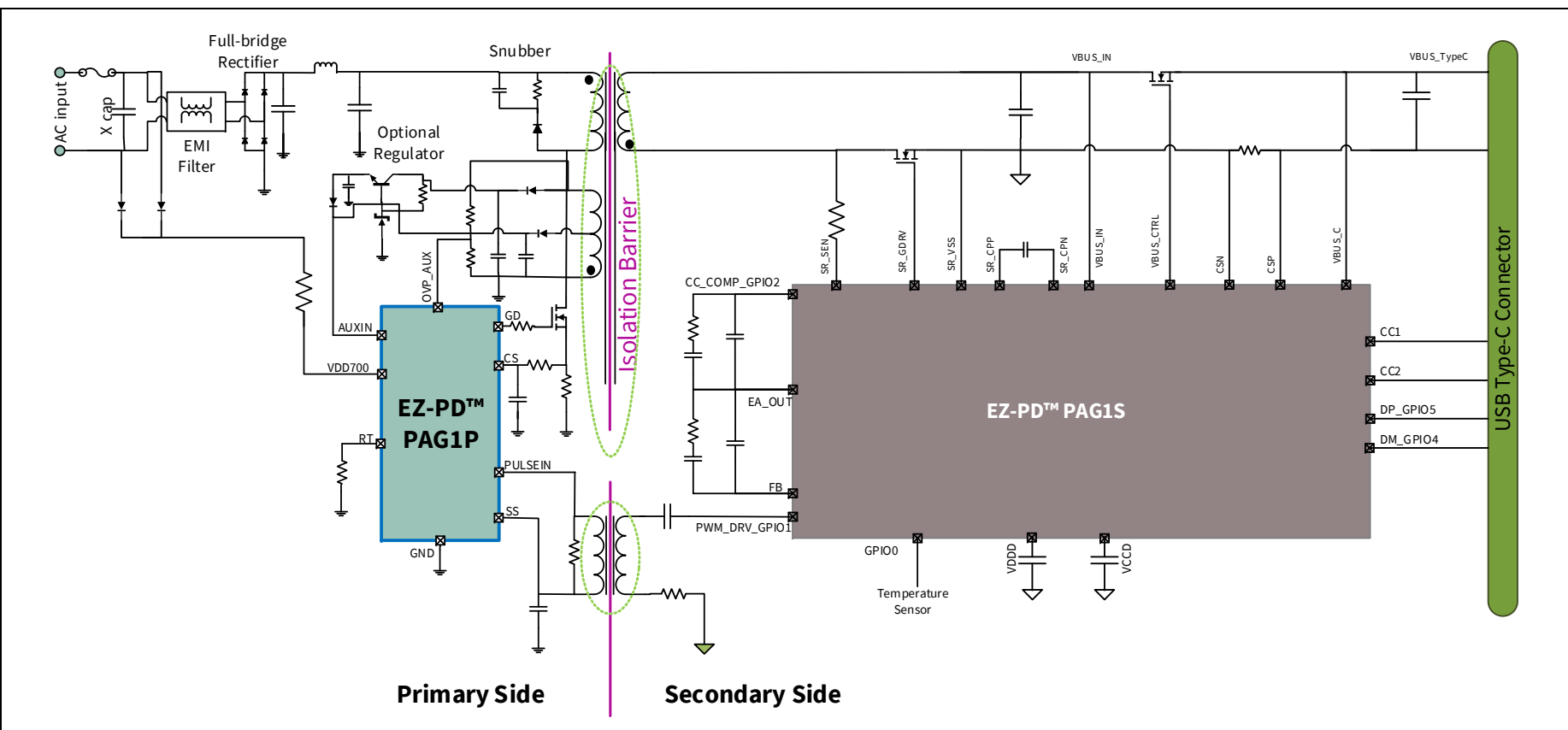


Figure 3 Type-C based mobile phone power adapter with EZ-PD™ PAG1P (CYPAP112xx) used in X-cap discharge configuration

3 Functional description

3.1 Soft-start

The Soft-start feature allows EZ-PD™ PAG1P to gradually increase the output voltage of the flyback converter till the secondary side takes control of the regulation. Soft-start is used during initial start-up sequence and fault condition. The duration of the soft-start is controlled by an external capacitor connected to the SS pin and the frequency of the soft-start is determined by an external resistor connected to the RT pin. An internal current source of 5 μ A charges the external capacitor and the maximum amplitude for the soft-start ramp is 3.75 V. 3.75 V dictates the maximum duty cycle. Under Soft-start, the maximum ON time of the primary FET is limited to 19 μ s which is equivalent to 70% duty cycle at 30 kHz. When the secondary side takes control, the maximum ON time is limited to 25 μ s.

3.2 X-cap mode

In EZ-PD™ PAG1P X-cap part, X-cap mode is detected when 3 V_VDD700UVRise transitions occur within 64 ms. A flag is set indicating the part is operating in X-cap mode. When 3 V_VDD700UVRise transitions are not detected within 64 ms after the flag is set, a line disconnect is detected and an internal discharge path is turned ON to discharge the X-capacitor.

3.3 Secondary synchronization

During the start-up phase, if EZ-PD™ PAG1P sees appropriate input pulses at the PULSEIN pin, then it synchronizes the primary FET control to the secondary pulses. The PWM control signal from the secondary side is coupled to the primary side using a Pulse Edge Transformer (PET). The PET is an important component to ensure proper frequency response and should have just an adequate Q-factor to avoid excessive overshoot. The positive pulse from the PET is treated as primary FET turn-on signal and the negative pulse from the PET is treated as primary FET turn-off signal. The pulse amplitude shall not exceed V_PULSEINNEGAMP and V_PULSEINPOSAMP and the pulse width shall be within T_PULSEINPW range.

The synchronization path between the secondary and primary through the PET is also used for communication of shutdown condition. Three consecutive negative pulses from the secondary side is treated as a shutdown signal. On receiving such three consecutive negative pulses, EZ-PD™ PAG1P will shutdown after 200 ms.

3.4 Power circuit

EZ-PD™ PAG1P integrates a high voltage start-up regulator. During power-up, EZ-PD™ PAG1P shall be powered from the line input via the VDD700 pin. Once voltage on the auxiliary winding is available from the secondary side, EZ-PD™ PAG1P switches its power supply input to AUX_IN pin and no power will be sourced from the VDD700 pin.

3.5 Overcurrent and overvoltage fault protection

EZ-PD™ PAG1P implements overcurrent protection. When the CS pin voltage exceeds V_CSTH1, EZ-PD™ PAG1P limits the primary current by turning OFF the primary FET.

EZ-PD™ PAG1P provides three types of voltage protection – protection against line undervoltage/overvoltage and secondary overvoltage. The line undervoltage/overvoltage monitoring is via VDD700 pin and the respective thresholds are V_VDDUVRise and V_VDDOVRise. Gate pulses are turned off until fault is removed. Once the voltage on VDD700 is within operating range, EZ-PD™ PAG1P does an auto-restart.

In addition, EZ-PD™ PAG1P monitors the voltage on OVP_AUX pin for detecting overvoltage condition on the secondary side. The voltage on the OVP_AUX pin is a scaled-down version of the secondary side voltage. When voltage on OVP_AUX exceeds V_OVPAUXRise, the gate driver is turned off. Once the voltage on OVP_AUX goes below the fault range, EZ-PD™ PAG1P does an auto-restart. EZ-PD™ PAG1P monitors secondary overvoltage only during start-up phase or during fault condition after auto-restart.

The flow chart in [Figure 4](#) and the [Functional block diagram](#) show the operation of the chip.

3.6 Auto-restart timer

A fixed timer of TAR sec is available for various fault conditions. The timer is operated from a free running oscillator inside EZ-PD™ PAG1P. Free running oscillator will be running at Fosc.

3.7 Protection and fault condition

Primarily there are four types of protection actions used in various fault conditions.

1. Autorestart: In this mode, EZ-PD™ PAG1P will wait TAR sec before doing a soft start. This sequence is repeated continuously (see [Figure 5](#)).
2. Latch or shutdown: No auto-restart timer or soft start is implemented. Shuts the IC immediately and power to the IC needs to be removed to unlatch.
3. Gate OFF: This only turns OFF the gate drive pulse and waits for the fault condition to pass before the IC functions normally.
4. Max duty cycle: Gate driver will be ON for 19 μ s (maximum) during soft-start. When secondary is in control, gate drive will be ON for 25 μ s (maximum).

Functional description

Table 2 provides the fault conditions and protection action.

Table 2 **Faults conditions and protection action**

Sl#	Fault	Action
1	VDD700 pin is under threshold voltage V_VDD700UVRise	Gate driver output is low. When VDD700 exceeds V_VDD700UVRise, do a soft-start followed by Autorestart.
2	VDD700 pin exceeds threshold voltage V_VDD700OVRise	Gate driver output is low during fault condition followed by Autorestart.
3	OVP_AUX pin exceeds threshold voltage V_OVPAUXRise	Gate driver output is low during fault condition followed by Autorestart. This is valid only when EZ-PD™ PAG1P is operating in open loop.
4	CS pin exceeds threshold voltage V_CSTH1	Gate driver output is low during fault condition. In open loop, do the Autorestart after fault condition is removed. In closed loop, wait for the next pulse from secondary side.
6	Stop command from Secondary side	Shutdown after 200 ms.
7	Receive no pulses from Secondary side for TAR sec after last stop pulse	Autorestart
8	Start pulse and no Stop pulse from Secondary side	Keep gate driver ON for 25 μ s. EZ-PD™ PAG1P will wait for TAR sec before doing Autorestart.

Functional description

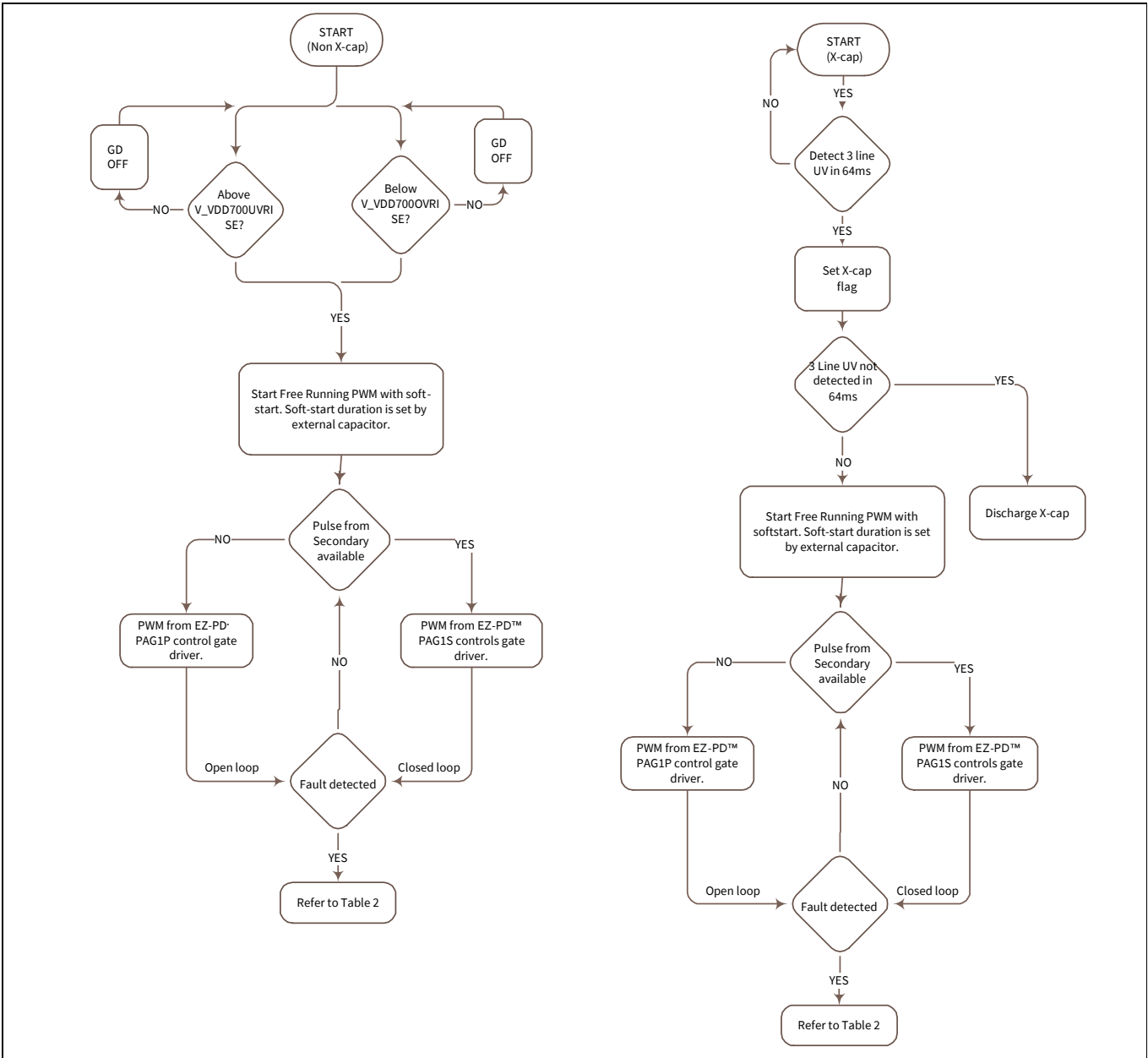


Figure 4 EZ-PD™ PAG1P operation flow chart

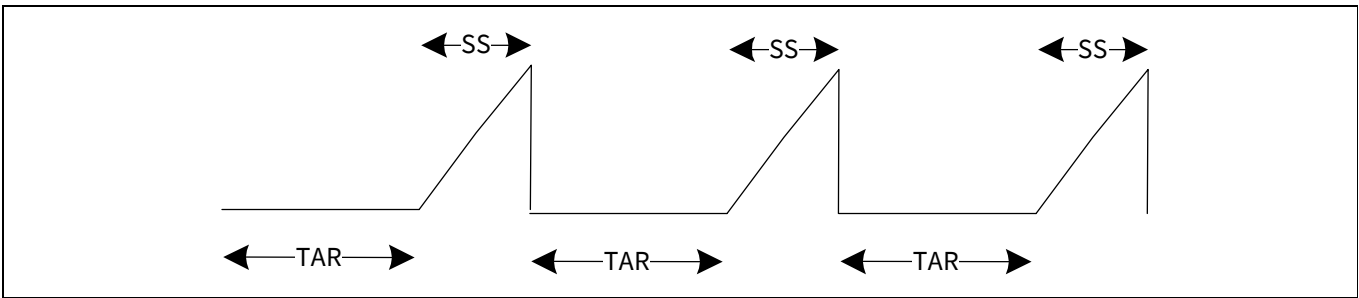


Figure 5 Auto-restart

Electrical specifications

4 Electrical specifications

Table 3 Absolute maximum ratings

Description	Min	Typ	Max	Unit	Details/conditions
Voltage on VDD700	0	—	500	V	—
Output current on GD	−1	—	1	A	—
Voltage on AUX_IN	0	—	22	V	—
Voltage on CS, SS, OVP_AUX	−0.3	—	8.25		—
Voltage on RT	0	—	8.25		—
Voltage on PULSEIN	−5	—	8.25		—
Operating junction temperature	−40	—	125	°C	—
Storage temperature	−55	—	150		—
Ambient temperature	−40	—	105		—
Electrostatic discharge human body model	2000	—	—	V	—
Electrostatic discharge charged device model	500	—	—		—
Pin current for latch-up	−100	—	100	mA	Except for SS and OVP_AUX. For SS and OVP_AUX, use −0.5 V. For RT, negative injection is not recommended.

Table 4 Silicon power specifications

Spec ID	Parameter	Description	Min	Typ	Max	Unit	Details/conditions
SID.VDD700.1	VDD700	High voltage supply	120	—	380	V	—
SID.AUXIN.1	V_AUXIN	Auxiliary supply	13	—	20		—
SID.PWR.1	I_VDD700_LATCH	Current from VDD700 (VDD700 = 325 V)	—	50	—	μA	EZ-PD™ PAG1P is in shutdown.
SID.PWR.2	I_VDD700_NOGD	Current from VDD700 (VDD700 = 325 V)	—	350	—		All circuits active except gate driver not toggling
SID.PWR.3	I_VDD700_ACTIVE	Current from VDD700 (VDD700 = 325 V)	—	800	—		All circuits active including gate driver toggling at 30 kHz; CL = 1 nF.
SID.PWR.4	I_AUXIN_NOGD	Current from AUXIN (AUXIN = 12 V)	—	350	—		All circuits active except gate driver not toggling
SID.PWR.5	I_AUXIN_ACTIVE	Current from AUXIN (AUXIN = 12 V)	—	800	—		All circuits active including gate driver toggling at 30 kHz; CL = 1 nF.
SID.PWR.6	I_VDD700_STARTUP	Current from VDD700 when starting up	—	10	—	mA	VDD700 = 325 V; AUXIN = 0 V
SID.PWR.7	I_XCAP_DISCHARGE	Current from VDD700 while discharging X-cap	0.48	1.7	2		—

Electrical specifications

Table 5 Undervoltage and overvoltage on VDD700

Spec ID	Parameter	Description	Min	Typ	Max	Unit	Details/conditions
SID.VDD700.2	V_VDD700UVRISE	Undervoltage rising threshold	90	100	115	V	—
SID.VDD700.3	V_VDD700UVFALL	Undervoltage falling threshold	81	90	110		—
SID.VDD700.4	V_VDD700OVRISE	Overvoltage rising threshold	400	430	490		—
SID.VDD700.5	V_VDD700OVFALL	Overvoltage falling threshold	395	420	480		—
SID.VDD700.6	T_VDD700UVDB	Debounce time undervoltage falling	—	30	—	ms	—

Table 6 Overvoltage on AUXIN

Spec ID	Parameter	Description	Min	Typ	Max	Unit	Details/conditions
SID.OVPAUX.1	V_OVPAUXRISE	Overvoltage threshold on OVP_AUX	1.1	1.2	1.26	V	—
SID.OVPAUX.3	T_OVPAUXBLK	Blanking time on OVP_AUX when GD output goes high to low	0.9	1.1	1.3	μs	—

Table 7 Gate driver

Spec ID	Parameter	Description	Min	Typ	Max	Unit	Details/conditions
SID.GD.1	V_GDVOL	GD Low Level Output voltage	—	1	2	V	AUXIN = 12 V and sinking 200 mA
SID.GD.2	V_GDVOH	GD High Level Output voltage	8	10	—		
SID.GD.3	T_GDTR	Rise time	—	25	60	ns	CL = 1 nF, AUXIN = 12 V
SID.GD.4	T_GDTF	Fall time	—	20	37		
SID.GD.5	T_GDPDR	Delay time from PULSEIN to GD, rising edge	—	90	125		
SID.GD.6	T_GDPDF	Delay time from PULSEIN to GD, falling edge	—	70	100		

Table 8 Current sense fault protection

Spec ID	Parameter	Description	Min	Typ	Max	Unit	Details/conditions
SID.CS.1	V_CSTH1	Threshold voltage pulse-by-pulse	430	500	550	mV	—
SID.CS.3	T_CSPD	Delay time from CS to GD	—	—	160	ns	CL = 1 nF
SID.CS.4	T_CSLEB	Leading edge blanking time	150	250	300		—

Electrical specifications

Table 9 PULSEIN

Spec ID	Parameter	Description	Min	Typ	Max	Unit	Details/conditions
SID.PULSEIN.1	V_PULSEINNEGAMP	Minimum negative going pulse amplitude	−4	−2	−	V	−
SID. PULSEIN.2	V_PULSEINPOSAMP	Maximum positive going pulse amplitude	−	2	4		−
SID. PULSEIN.3	T_PULSEINPW	Pulse Width	25	−	200	ns	−

Table 10 Free running oscillator

Spec ID	Parameter	Description	Min	Typ	Max	Unit	Details/conditions
SID.OSC.1	FOSC	Frequency	27	30	38	kHz	$F_{OSC} = (I_{RTCURR}) * (1/5 \text{ pF}) * (1/4 \text{ V}) = 30 \text{ kHz}$
SID.OSC.2	DCMIN	Minimum duty cycle	3	−	−	%	−
SID.OSC.3	DCMAX	Maximum duty cycle	−	−	70		−

Table 11 Timing resistor

Spec ID	Parameter	Description	Min	Typ	Max	Unit	Details/conditions
SID.RT.1	RT	Timing resistor	−	$499 \pm 1\%$	−	k Ω	−
SID.RT.2	I_RTCURR	Current through RT	−	$2.4 \pm 5\%$	−	μA	−

Table 12 Auto-restart time

Spec ID	Parameter	Description	Min	Typ	Max	Unit	Details/conditions
SID.AR.1	TAR	Auto-restart time	−	2	−	Seco nds	−

Table 13 Soft-start capacitor charging current

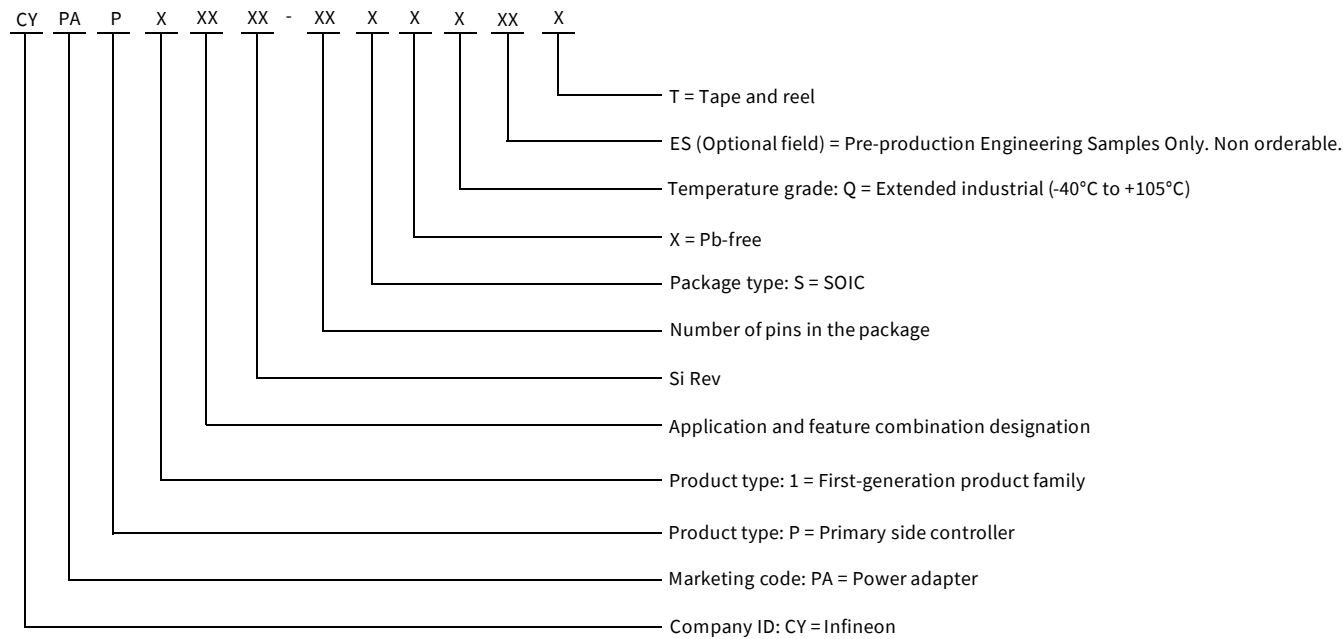
Spec ID	Parameter	Description	Min	Typ	Max	Unit	Details/conditions
SID.SS.1	I_SSCURR	Current for charging soft-start capacitor	−	4.8	6	μA	Soft-start time = $I/C \text{ V/s}$; Maximum soft-start voltage is 3.75 V and start of soft-start is 1 V.

5 Ordering information

Table 14 Ordering part number

MPN	Mode	Package type	Silicon revision
CYPAP111A3-10SXQ	Non X-cap	10-pin SOIC	A3
CYPAP111A3-10SXQT			
CYPAP112A3-10SXQ	X-cap		
CYPAP112A3-10SXQT			

5.1 Ordering code definitions



6 Packaging

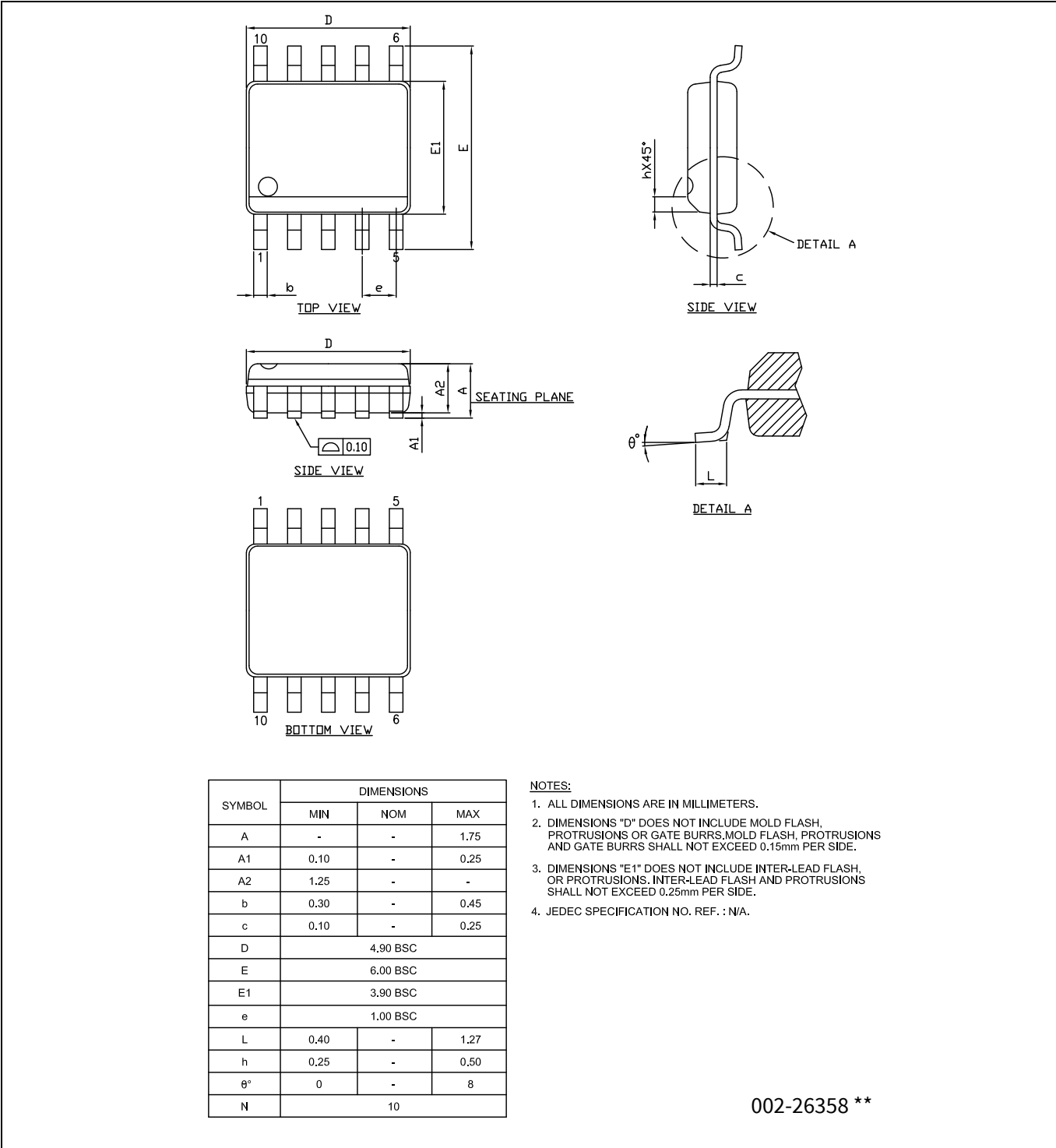


Figure 6 10-pin SOIC package outline

Revision history

Document version	Date of release	Description of changes
*D	2019-12-10	Changed datasheet status to final
*E	2020-06-18	Updated SID.OSC.1 parameter min value from 24 to 27 and max value from 36 to 38 in Table 10
*F	2022-05-18	Updated to Infineon template Changed part numbers from CYPAP111A3-10SXQES and CYPAP112A3-10SXQES to CYPAP111A3-10SXQT and CYPAP112A3-10SXQT in “Ordering information” on page 14

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